

Product Summary

The GESDBNKPC4M features 400W (@8/20us) of power handling capability to accommodate the higher transient voltage levels which may be expected in extended common mode applications. This provides higher equipment reliability and eliminates the "guesswork" required when using zener diodes that are not rated to handle such transient conditions.

The GESDBNKPC4M replaces four discrete components by integrating two 12V and two 7V TVS diodes in a single package. The integrated design aids in reducing voltage over-shoot associated with trace inductance. The low clamping voltage of the GESDBNKPC4M minimizes the stress on the protected transceiver.

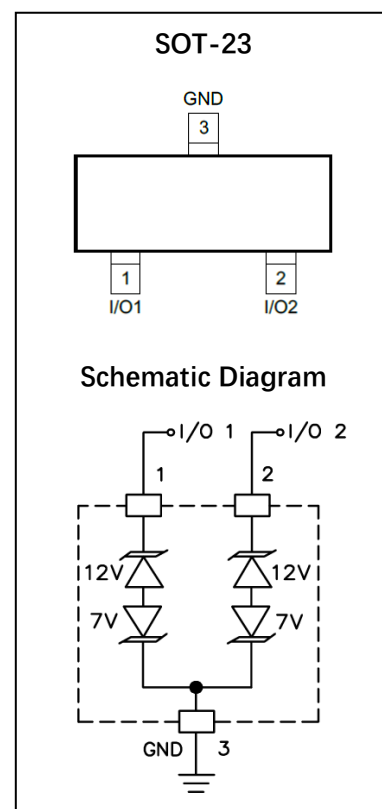
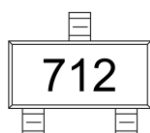
Feature

- Transient protection for each line according to IEC61000-4-2 (ESD): $\pm 30\text{kV}$ (air discharge)
IEC61000-4-2 (ESD): $\pm 30\text{kV}$ (contact discharge)
IEC61000-4-4 (EFT): 40A (5/50ns)
IEC61000-4-5 (surge): 17A (8/20 μs)
- low capacitance: $C_J = 75\text{pF}$ typ.
- Low leakage current
- Low clamping voltage
- Solid-state silicon technology

Application

- Security systems
- Protection of RS-485 transceivers with extended common-mode range
- Automatic Teller Machines
- HFC systems
- Networks

Marking:



Absolute Maximum Ratings ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

Parameter		Symbol	Value	Unit
IEC 61000-4-2 ESD Voltage	Air Model	$V_{\text{ESD}}^{1)}$	± 30	kV
	Contact Model		± 30	
Peak Pulse Power		$P_{\text{PP}}^{2)}$	400	W
Peak Pulse Current		$I_{\text{PP}}^{2)}$	17	A
Lead Solder Temperature – Maximum (10 Second Duration)		T_L	260	$^{\circ}\text{C}$
Junction Temperature		T_J	-55~ +150	$^{\circ}\text{C}$
Storage Temperature Range		T_{STG}	-55~ +150	$^{\circ}\text{C}$

- 1) Device stressed with ten non-repetitive ESD pulses.
- 2) Non-repetitive current pulse 8/20 μs exponential decay waveform according to IEC61000-4-5.

ESD Standards Compliance

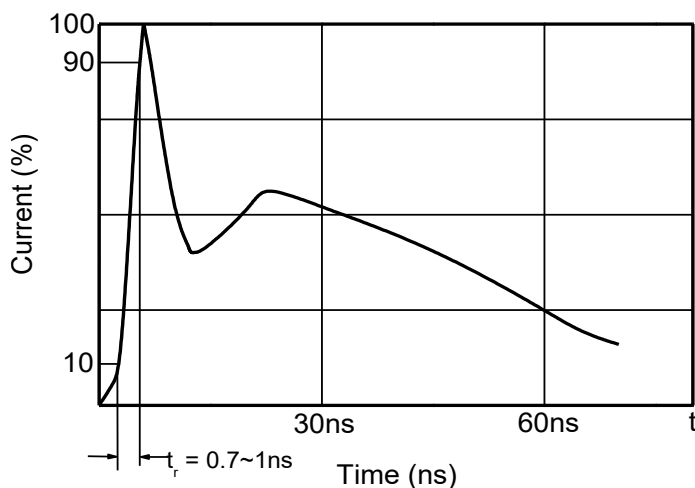
IEC61000-4-2 Standard

Contact Discharge		Air Discharge	
Level	Test Voltage kV	Level	Test Voltage kV
1	2	1	2
2	4	2	4
3	6	3	8
4	8	4	15

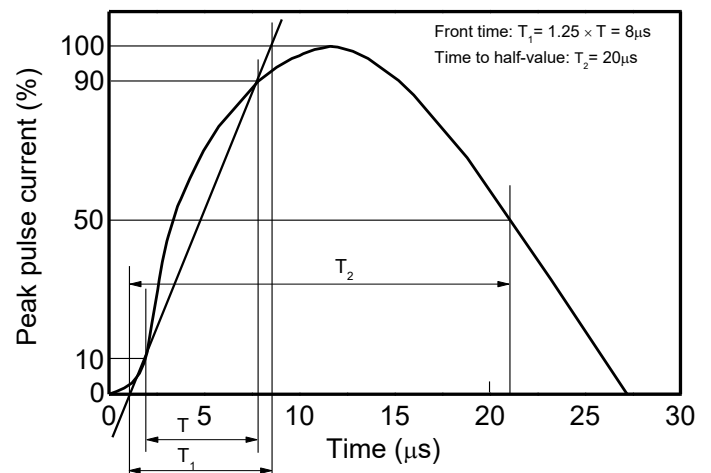
JESD22-A114-B Standard

ESD Class	Human Body Discharge V
0	0~249
1A	250~499
1B	500~999
1C	1000~1999
2	2000~3999
3A	4000~7999
3B	8000~15999

Contact discharge current waveform per IEC61000-4-2

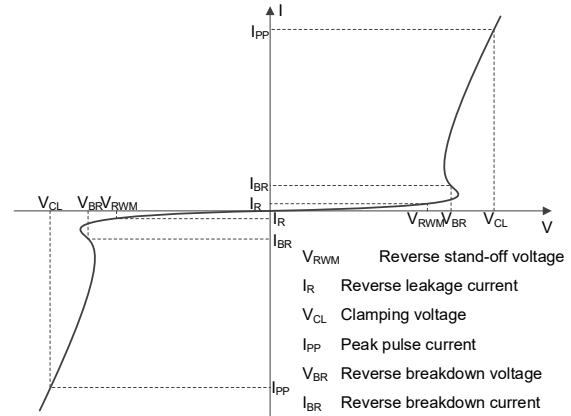


8/20 μs waveform per IEC61000-4-5



Electrical Parameter

Symbol	Parameter
V _C	Clamping Voltage @ I _{PP}
I _{PP}	Peak Pulse Current
V _{BR}	Breakdown Voltage @ I _T
I _T	Test Current
I _R	Reverse Leakage Current @ V _{RWM}
V _{RWM}	Reverse Standoff Voltage



V-I characteristics for a Bi-directional TVS

Electrical Characteristics(T_A=25°C unless otherwise specified)

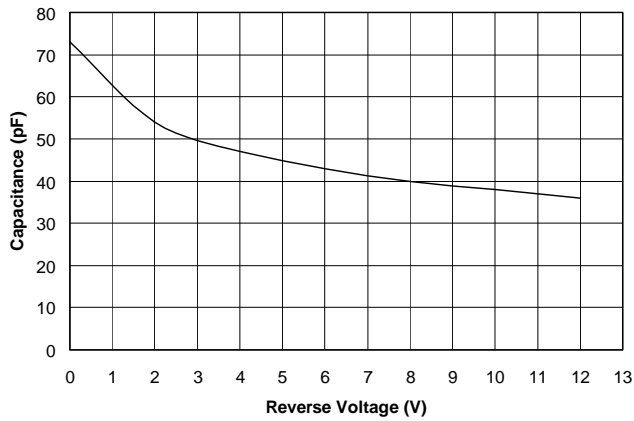
Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Reverse Stand-Off Voltage	V _{RWM} ¹⁾	Pin 1/2 to Pin 3			12	V
Reverse Leakage Current	I _R	V _R = 12V			1	nA
Breakdown Voltage	V _{BR}	I _T =1mA	13.3			V
Clamping Voltage	V _C ²⁾	I _{PP} =5A			20	V
		I _{PP} =17A			26	V
Junction Capacitance	C _J	V _R =0V, f=1MHz			75	pF

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Reverse Stand-Off Voltage	V _{RWM} ¹⁾	Pin 3 to Pin 1/2			7	V
Reverse Leakage Current	I _R	V _R = 7V			20	nA
Breakdown Voltage	V _{BR}	I _T =1mA	7.5			V
Clamping Voltage	V _C ²⁾	I _{PP} =5A			10	V
		I _{PP} =17A			12	V
Junction Capacitance	C _J	V _R =0V, f=1MHz			75	pF

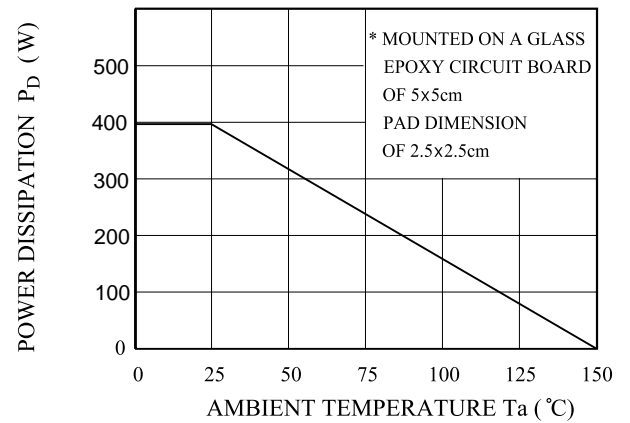
Notes:

- 1) Other voltages available upon request.
- 2) Non-repetitive current pulse 8/20μs exponential decay waveform according to IEC61000-4-5.

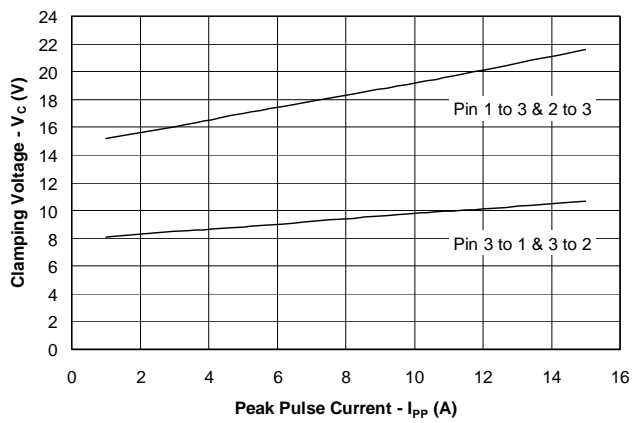
Typical Characteristics



Capacitance vs. Reverse Voltage

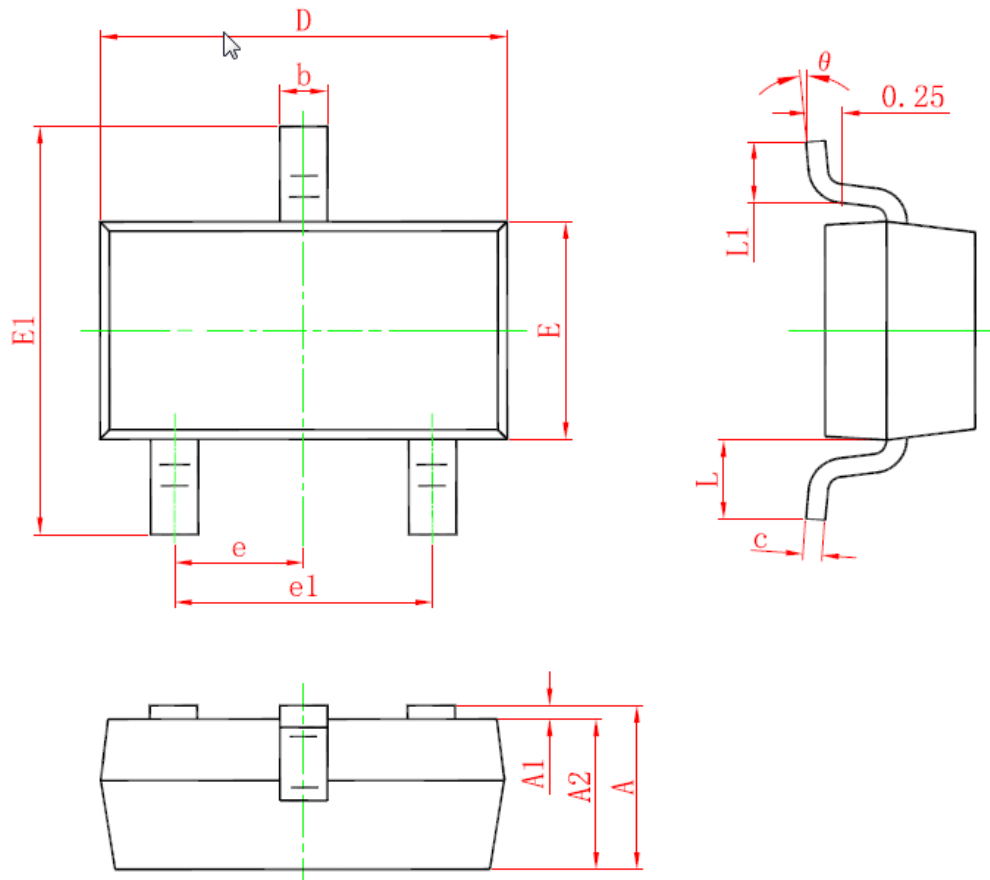


P_D - T_a



Clamping Voltage vs. Peak Pulse Current

SOT-23 Package Information



Symbol	Dimensions in millimeter		Dimensions in Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950TYP		0.037TYP	
e1	1.800	2.000	0.071	0.079
L	0.550REF		0.022REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

Attention:

- GreenPower Electronics reserves the right to improve product design function and reliability without notice.
- Any and all semiconductor products have certain probability to fail or malfunction, which may result in personal injury, death or property damage. Customers are solely responsible for providing adequate safe measures when design their systems.
- GreenPower Electronics products belong to consumer electronics or other civilian electronic products.